

STTH61R04TV

Ultrafast recovery diode

Main product characteristics

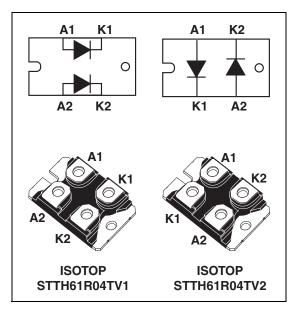
I _{F(AV)}	2 x 30 A
V _{RRM}	400 V
Тј	150° C
V _{F (typ)}	0.95 V
t _{rr (typ)}	24 ns

Features and benefits

- Ultrafast
- Very low switching losses
- High frequency and high pulsed current operation
- Low leakage current
- Insulated package:
 - ISOTOP
 Electrical insulation = 2500 V_{RMS}
 Capacitance = 45 pF

Description

The STTH61R04TV series uses ST's new 400 V planar Pt doping technology. The STTH61R04 is specially suited for switching mode base drive and transistor circuits, such as welding equipment.



Order codes

Part Number	Marking
STTH61R04TV1	STTH61R04TV1
STTH61R04TV2	STTH61R04TV2

1 Characteristics

Table 1.	Absolute ratings (limiting values per diode at 25° C, unless otherwise specified)
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Symbol	Parameter					Unit
V _{RRM}	Repetitive peak reverse voltage				400	V
V _{RSM}	Non repetitive peak reverse voltage				400	V
I _{F(RMS)}	RMS forward current			60	А	
I _{F(AV)}	Average forward current, $\delta = 0.5$	Per diode $T_c = 80^{\circ} C$			30	А
I _{FRM}	Repetitive peak forward current	$t_p = 5 \ \mu s$, F = 1 kHz square			900	А
I _{FSM}	Surge non repetitive forward current t _p = 10 ms Sinusoidal				350	А
T _{stg}	Storage temperature range					°C
Тj	Maximum operating junction temperature				150	°C

Table 2.Thermal parameters

Symbol	Parameter		Value	Unit
P	Junction to case	Per diode	1.5	
R _{th(j-c)}	Total	Total	0.8	° C/W
R _{th(c)}	Coupling thermal resistance		0.1	

When the diodes are used simultaneously:

 $\Delta T_{j(diode1)} = P_{(diode1)} \times R_{th(j-c)} (per diode) + P_{(diode2)} \times R_{th(c)}$

Table 3. Static electrical characteristics

Symbol	Parameter	Test conditions		Min.	Тур	Max.	Unit
I _B ⁽¹⁾	Reverse leakage current	$T_j = 25^\circ C$	V - V			15	
'R` ′	neverse leakage current	e current $T_j = 125^{\circ} C$ $V_R = V_{RRM}$		15	150	μA	
		T _j = 25° C				1.45	
$V_F^{(2)}$	Forward voltage drop	T _j = 100° C	I _F = 30 A		1.05	1.3	V
		T _j = 150° C]		0.95	1.20	

1. Pulse test: $t_p = 5 \text{ ms}, \delta < 2 \%$

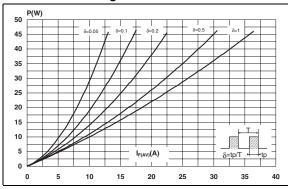
2. Pulse test: $t_p = 380 \ \mu s, \ \delta < 2 \ \%$

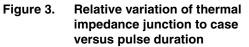
To evaluate the conduction losses use the following equation: P = 0.9 x $I_{F(AV)}$ + 0.01 x ${I_F}^2_{(RMS)}$

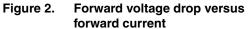
Symbol	Parameter Test conditions		Min.	Тур	Max.	Unit
	Reverse recovery time	$\begin{array}{l} I_F=1 \text{ A, } dI_F/dt=-50 \text{ A/}\mu \text{s,} \\ V_R=30 \text{ V, } T_j=25^\circ \text{ C} \end{array}$			65	
t _{rr}		$I_F = 1 \text{ A, } dI_F/dt = -100 \text{ A/}\mu\text{s},$ $V_R = 30 \text{ V, } T_j = 25^{\circ} \text{ C}$		31	45	ns
		$ I_F = 1 \text{ A, } dI_F/dt = -200 \text{ A}/\mu\text{s}, \\ V_R = 30 \text{ V, } T_j = 25^\circ \text{ C} $		24	35	
I _{RM}	Reverse recovery current	I _F = 30 A, dI _F /dt = -200 A/μs, V _R = 320 V, T _j = 125° C		10	14	А
S Softness factor		I _F = 30 A, dI _F /dt = -200 A/μs, V _R = 320 V, T _j = 125° C		0.4		
t _{fr}	Forward recovery time	$ I_F = 30 \text{ A} dI_F/dt = 100 \text{ A}/\mu \text{s} \\ V_{FR} = 1.5 \text{ x} \text{ V}_{Fmax}, \text{T}_j = 25^\circ \text{ C} $		250		ns
V _{FP}	Forward recovery voltage	$I_F = 30 \text{ A}, \text{ d}I_F/\text{d}t = 100 \text{ A}/\mu\text{s},$ $T_j = 25^{\circ} \text{ C}$		2.9		v

Table 4.Dynamic characteristics

Figure 1. Conduction losses versus average current







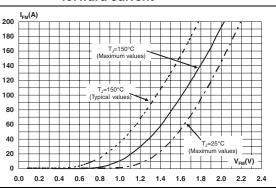
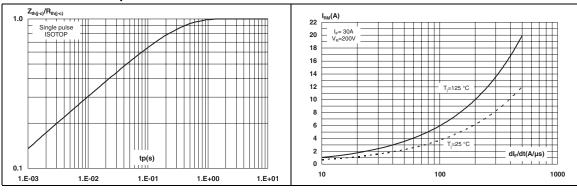


Figure 4. Peak reverse recovery current versus dl_F/dt (typical values)



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Figure 5. Reverse recovery time versus dl_F/dt (typical values)

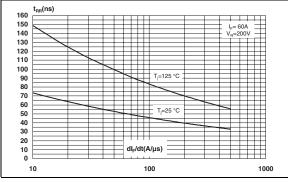
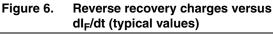
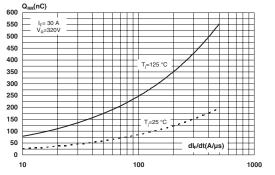
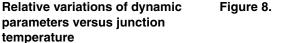
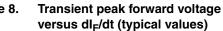


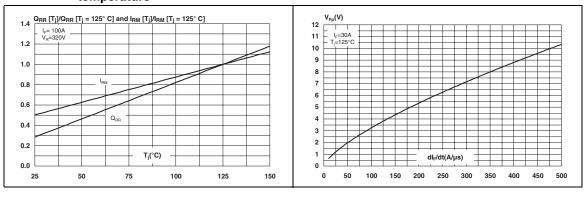
Figure 7. **Relative variations of dynamic** parameters versus junction





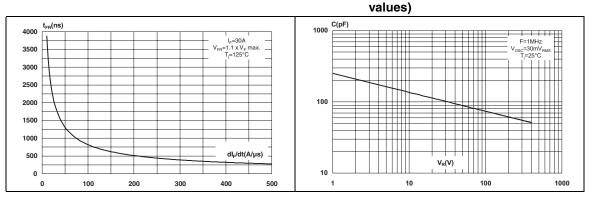






Forward recovery time versus dl_F/dt Figure 10. Figure 9. (typical values)

Junction capacitance versus reverse voltage applied (typical

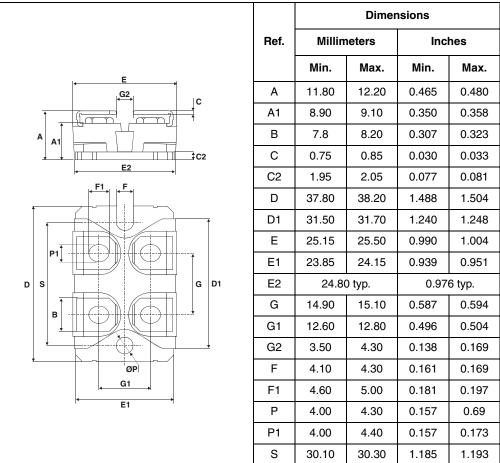


2 Package information

Epoxy meets UL94, V0

Cooling method: by conduction (C)





In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.



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3 Ordering information

I	Part Number	Marking	Package	Weight	Base qty	Delivery mode
I	STTH61R04TV1	STTH61R04TV1	ISOTOP	27 g	10	Tube
I	STTH61R04TV2	STTH61R04TV2	ISOTOP	27 g	10	Tube

4 Revision history

Date	Revision	Description of Changes
31-Mar-2007	1	First issue

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